

IT8700P+

High Speed Multi-channel DC Electronic Load



Your Power Testing Solution



IT8700P+ High Speed Multi-channel DC Electronic Load



IT8700P+ series high-speed multi-channel DC electronic load is an upgraded version of the original IT8700P series with higher speed and higher precision. Its modules support master-slave paralleling connection for power extension. It's compatible with IT8700P mainframe, the new modules and old modules can work together. The IT8700P+ modules have faster dynamic response and can make the minimum rise time of current less than rising time of minimum current < 10 µs. In addition, the low internal resistance makes it suitable for low-voltage loading test. Faster loop speed can accurately control current without overshoot which improves test efficiency. Furthermore, it has three current ranges for higher accuracy and lower ripple. The voltage and current measurement speed of this series has been upgraded to 250kHz. It has built-in LAN, USB and RS232 interfaces, and supports SCPI protocol. Therefore, IT8700P+ is good for system integration and is suitable for R&D and production line testing of super capacitors, fuel cells, lithium ion batteries, high-speed AC-DC and DC-DC power supplies such as computer power supplies and communication power supplies.

FFATURE

- Three-stage current range, higher accuracy and lower ripple
- Supports master-slave parallel connection of 16-channel modules, flexibly extends power
- Faster dynamic response, minimum current rise time < 10 μs
- Stable operation down to zero volts, suitable for low-voltage capacitors, solar cells, fuel cells, and other low-voltage high current power supplies
- Faster loop speed, precise control of current without overshoot
- The voltage and current measurement speed is upgraded to 250kHz, good for system integration
- Comprehensive protection functions: OVP/OCP/OPP/OTP, Sense protection
- *1 Current is no more than 15A if connecting with front terminals

Model	Voltage	Current	Power
IT8723P+	80 V	45 A	2 x 300 W
IT8732P+	80 V	60 A	400 W
IT8733P+	80 V	120 A	600 W

- Compatible with IT8700P mainframe, old and new modules can be matched
- Short-circuit peak current measurement function
- Available front/rear terminals*1
- 8 operating modes: CC/ CV/ CR/ CW/ CV+CC/ CR+ CC/ CW+CC/ CV+CR (CR-LED)
- Automatic test function to tell whether the test results exceed the set specifications
- Built-in LAN, USB, RS232 interfaces
- CV loop speed is adjustable to match different DUTs
- Multi channel synchronous control

Main Frame	
IT8701P	Mainframe for 2 modules (including three interfaces)
IT8702P	Mainframe for 4 modules (including three interfaces)
IT8703P	Expansion mainframe for 4 modules

Applications



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Flexible modules combination

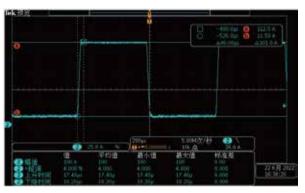
The IT8700P+ series is designed with removable modules, so that you can choose different modules according to your needs. These modules can work with the original IT8700P series modules too. There are high-performance microprocessor chips in each load module and mainframe. Parallel architecture is adopted to achieve faster testing. The load modules are controlled synchronously by the system, and the power supply with multiple outputs can also be tested synchronously.

Low voltage loading, stable operation down to zero volts

The IT8700P+ module has ultra-low on-resistance and three ranges. Under the medium and small range, the minimum load voltage is <0.1V. In the high current range, the minimum load voltage at full current is <0.5V, and lower input impedance can be obtained after parallel connection. It is suitable for testing fuel cells, supercapacitors, solar cells, DC-DC converters and other low voltage and high current electronic devices.

Fast dynamic response

Power supplies often have high requirements for instantaneous signals and dynamic response. In order to meet faster and faster testing requirements, IT8700P+ series provides high-speed, programmable dynamic sequence control. The current rise time is no more than 10 µs, much faster than the last generation. So it can be used for high-speed dynamic test of communication power supply and computer power supply. There are three modes of the dynamic test function, namely continuous mode, pulse mode and toggle mode.



IT8733P+ (80V,120A,600W) 10A~110A dynamic waveform (current slope 5A/us)

Master-slave parallel connection

The IT8700P+ series supports master-slave parallel connection, 8 units (16 channels) at most can be connected in parallel, and the power can be extended to 4800W. The synchronization time error is 4us between paralleled units, and current equally assigning accuracy is 0.1%+0.1%F.S. Thanks to the flexible power extension, it can be used to test various DUTs and increase equipment utilization. The current sharing mode makes no sacrifice of the dynamic performance after parallel connection.

3 current ranges, well applied to Energy Star standard test for consumer electronics products

IT8700P+ provides 3 current ranges and higher measurement accuracy for DUTs that require high current accuracy like batteries. No need to build a complex test bench, the low current range of the IT8700P+ can be used for Energy Star standard testing in sleep, idle and standby modes of consumer electronics products. Actually it is suitable for almost all consumer electronics products that require precise current setting and measurement at the µA and mA levels.

Fast measurement of I-V characteristic

The voltage and current measurement of IT8700P+ is fast (up to 250kHz). It can be applied to various testing applications such as charging piles, automotive electronics; renewable energy and so on.

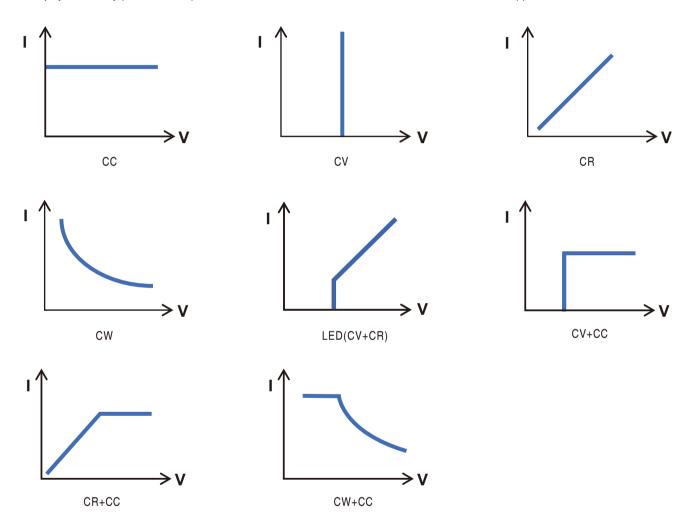


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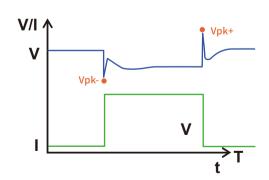
8 operation modes

Besides the four basic operation modes of CC/CV/CR/CW, IT8700P+ provides additional 4 compound operation modes : CV/ CC/ CR+CC/CW+CC/CV+CR(CR-LED). Under CV/CR/CW operation mode, the maximum current (I-Limit) is settable. This can effectively solve the problem of instantaneous surge current during testing and avoid triggering DUT's protection, or even burning out or any other injury caused by possible misoperation or environmental factors. So it can be used in various applications.



Peak voltage measurement(Vpk)

When measuring the dynamic current of a switching power supply, an oscilloscope was usually necessary to capture the instantaneous voltage and current waveforms and obtain Vpk+ and Vpk- accordingly. But with digital data acquisition function, IT8700P can directly obtain the Vpk+ and Vpk- values without an oscilloscope.



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IT8700P+ High Speed Multi-channel DC Electronic Load

IT8700P+ Specification

Para	meter			IT8723P+			
	Voltage		0.1~18V			0.1~80V	
	Current	$ m 0 \sim 0.9A$		$ m 0 \sim 4.5A$		0~45A	
	Power	0 ~ 60W			0~30	0~300W	
Rated value	Resistance		$0.05\Omega\sim 10$	Ω		0.05Ω \sim 7500Ω	
nateu value	Min. resistance	≒50mΩ		≐15	≒15mΩ		
	MOV	0.06V at 0.9A		0.07V at 4.5A	. 10	0.7V at 45A	
	Input leak current	0.00V at 0.5A	0.06mA	0.07 V at 4.5A		0.2mA	
	Voltage		1mV			10mV	
	Current	0.1 m A	IIIIV	0.1mA			
Set resolution	Power	0.1mA		0.1mA		1mA	
oot rocoldiion				10mW			
	Resistance	16bit					
Readback	Voltage		0.1 mV			1 mV	
resolution	Current	0.1mA		0.1mA		1mA	
	Power	10mW					
	Voltage	±(0.05%+0.025%FS)				±(0.05%+0.025%FS)	
	Current	±(0.1%+0.1%FS)		±(0.05%+0.05%F	,	±(0.05%+0.05%FS)	
Set accuracy	Power *3			0.2%+0.2%FS			
	Resistance*1		0.01%+0.085	S *2		0.01%+0.0008S	
Doodhack	Voltage			±(0.025%+0.025%			
Readback	Current	±(0.1%+0.1%FS)			±(0.05%+0	.05%FS)	
accuracy	Power	•		±(0.2%+0.2%FS			
Set temperature drift	Voltage			≤100ppm/°C + 100ppn			
oefficient(% of Output/ C +Offset)	Current	≤100ppm/°C + 100ppm/°C*FS					
Readback Temperature	Voltage			≤100ppm/°C + 100ppn			
rift coefficient((% of Output/ C+Offset)	Current			≤100ppm/°C + 100ppn			
output C +Oliset)	Rising	0.0001 \sim 0.09A/uS		$0.0001 \sim 0.45$ A		0.001 \sim 4.5A/uS	
Dynamic	Falling	$0.0001 \sim 0.09 \text{A/uS}$ $0.0001 \sim 0.09 \text{A/uS}$		$0.0001 \sim 0.45 \text{A}$		0.001 ~ 4.5A/uS	
,	Min.rising time*5			= 10uS	uo		
esponse *4		≒10uS		- 10uS 0.001 ∼ 20KH;	,	≒10uS	
	Dynamic frequency Voltage	110V ±10% or 220V ±10%					
	•				1070		
AC parameter	Frequency	50/60Hz					
	lmax.	0.3A					
	Power factor	≥0.99					
Set stability-30min(%	Voltage		±(0.05%+0.025%F	,		±(0.05%+0.025%FS)	
f Output/°C +Offset)	Current	±(0.1%+0.1%FS)		±(0.05%+0.05%FS)		±(0.05%+0.05%FS)	
Set stability-8h(% of	Voltage		±(0.05%+0.025%l			±(0.05%+0.025%FS)	
Output/ C+Offset)	Current	±(0.1%+0.1%FS)		±(0.05%+0.05%FS)		±(0.05%+0.05%FS)	
eadback stability-30min	Voltage			±(0.025%+0.025%F	S)		
% of Output/ C+Offset)	Current	±(0.1%+0.1%FS)			±(0.05%+0.	05%FS)	
eadback stability-8h	Voltage			±(0.025%+0.025%	FS)	,	
% of Output/°C +Offset)	Current	±(0.1%+0.1%FS)			±(0.05%+0.	05%FS)	
Sense voltage				≤2V			
Storage temperature				-20°C∼ 70°C			
Ç	OPP	66W		310W		310W	
Danie d'a	OCP	0.99A		4.95A		49.5A	
Protection	OVP	0.0071	18.5V	7.00/1		85V	
	OTP		10.04	95°C		001	
ntorfaces	011			Ether Net, GPIB, US	B BS232		
nterfaces					J, 110202		
solation(output to ground)		500V/DC/1mA					
solation(input to ground)				1.5KV/AC/5mA			
Units parallel connected				≤16(channel)			
Protection level				IP20			
Safety regulation				IEC 61010			
Cooling				fan			
Working temperature				$0\sim40^{\circ}\mathrm{C}$			
Dimension(mm)				82mm*183mm*573m	m		
N.W.		5kg					

^{*1} Input voltage/current is not less than 10%FS (FS is full scale)

^{*2} Range of resistance readback value: (1/(1/R+(1/R)*0.01%+0.08),1/(1/R-(1/R)*0.01%-0.08))

^{*3} Input voltage/current is not less than 10%FS

^{*4} The loading current is not less than 2%FS

^{*5} Minimum rise time: 10%~90% of current rise time

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IT8700P+ Specification

Para	meter			IT8732P+			
	Voltage		0.1 \sim 18V			0.1 ∼ 80V	
	Current	\sim 1.2A		$0\sim 6A$		0 ∼ 60A	
	Power	0 ∼ 96W		U UN	0 ~ 4		
Datad value	Resistance	0 00	$0.05\Omega\sim 10\Omega$		U 7	$0.05\Omega{\sim}7500\Omega$	
Rated value	Min. resistance				≒15m		
	MOV			0.0E\/ a+ 6A	- 1511	0.5V at 60A	
	Input leak current	0.06V at 1.2A	0.06m1	0.05V at 6A			
			0.06mA			0.2mA	
	Voltage	0.4.4	1mV	0.4.4		10mV	
et resolution	Current	0.1mA		0.1mA		1mA	
Set resolution	Power			10mW			
	Resistance	16bit					
leadback	Voltage		0.1 mV			1 mV	
esolution	Current	0.1mA		0.1mA		1mA	
SOlution	Power			10mW			
	Voltage		±(0.05%+0.025%FS)			±(0.05%+0.025%FS)	
	Current	±(0.1%+0.1%FS)		±(0.05%+0.05%FS)		±(0.05%+0.05%FS)	
et accuracy	Power *3	,		0.2%+0.2%FS		,	
•	Resistance*1		0.01%+0.08S *2			0.01%+0.0008S	
	Voltage			±(0.025%+0.025%FS)			
eadback	Current	±(0.1%+0.1%FS)		_(0.020 /010.020 /010)	±(0.05%+0.0	5%FS)	
ccuracy	Power	±(0.170+0.1701 0)		±(0.20/±0.20/ES)	±(0.0570∓0.0	3701 0)	
et temperature drift	Voltage	±(0.2%+0.2%FS)					
efficient(%of		≤100ppm/°C +100ppm/°C*FS					
utput/ C +Offset) adback Temperature	Current	≤100ppm/°C + 100ppm/°C*FS					
ft coefficient((% of	Voltage	≤100ppm/°C + 100ppm/°C*FS					
utput/ C+Offset)	Current		\leq 100ppm/°C + 100ppm/°C*FS				
	Rising *4	$0.0001 \sim 0.1 \text{A/uS}$		$0.0001 \sim 0.5 \text{A/uS}$		0.001 \sim 5A/uS	
ynamic	Falling*4	0.0001 ~ 0.1A/uS		0.0001 ~ 0.5A/uS		0.001 \sim 5A/uS	
esponse	Min.rising time*5	≒10uS		≒10uS		≒10uS	
	Dynamic frequency	0.001 \sim 20KHz					
	Voltage		1	10V ±10% or 220V ±10%)		
	Frequency			50/60Hz			
C parameter	lmax.			0.3A			
	Power factor			≥0.99			
et stability-30min(%	Voltage	±	(0.05%+0.025%FS)			±(0.05%+0.025%FS)	
Output/ C+Offset)	Current	±(0.1%+0.1%FS)	(0.007.0.0000)	±(0.05%+0.05%FS)		±(0.05%+0.05%FS)	
et stability-8h(%of		,	(0.05%+0.025%FS)	_(,,,		±(0.05%+0.025%FS)	
utput/°C+Offset)	Current	±(0.1%+0.1%FS)	(0.007010.0207010)	±(0.05%+0.05%FS)		±(0.05%+0.05%FS)	
adback stability-30min	Voltage	=(0.17010.17010)		±(0.025%+0.025%FS)		_(0.007010.007010)	
of Output/ C+Offset)	Current	±(0.1%+0.1%FS)		±(0.02070±0.020701 0)	±(0.05%+0.05	E0/ EQ)	
adback stability-8h		±(0.170±0.1701 σ)		. (0.00E0/ . 0.00E0/ EC)	±(0.05%+0.05	5%F5)	
of Output/ C +Offset)	Voltage	±(0.10/±0.10/EQ)		±(0.025%+0.025%FS)	±(0.05%±0.06	50/ EQ)	
	Current	±(0.1%+0.1%FS)		-01/	±(0.05%+0.05	5%F3)	
ense voltage				≤2V			
torage temperature				-20°C∼ 70°C			
	OPP	100W		410W		410W	
rotection	OCP	1.32A		6.6A		66A	
	OVP		18.5V			85V	
	OTP			95°C			
terfaces			Eti	her Net, GPIB, USB,	RS232		
lation(output to ground)				500V/DC/1mA			
lation(input to ground)		1.5KV/AC/5mA					
its parallel connected				≤16(channel)			
rotection level				IP20			
				IEC 61010			
afety regulation							
ooling				fan			
orking temperature				0 ~ 40°C			
Dimension(mm)				82mm*183mm*573mm			
1.W.				5kg			

^{*1} Input voltage/current is not less than 10%FS (FS is full scale)

 $^{^*2}$ Range of resistance readback value: ($1/(1/R+(1/R)^*0.01\%+0.08), 1/(1/R-(1/R)^*0.01\%-0.08)$)

^{*3} Input voltage/current is not less than 10%FS

^{*4} Rise/fall slew rate: 10%~90% of current rising from 0 to Max.current

^{*5} Minimum rise time: 10%~90% of current rise time

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IT8700P+ Specification

Para	meter		IT8733P+				
	Voltage	0.1	\sim 18V	0.1 ∼ 80V			
	Current	0 ∼ 2.4A	\sim 12A	$ m 0 \sim 120A$			
	Power	$_{ m 0}$ \sim 120W		$_{ m 0}$ \sim 600W			
Rated value	Resistance	0.05Ω	\sim 10 Ω	$10\Omega{\sim}7500\Omega$			
	Min. resistance	⇒50mΩ	≒13mΩ				
	MOV	0.12V at 2.4A	0.15V at 12A	1.5V at 120A			
	Input leak current						
	Voltage	0.06 1n		0.3mA 10mV			
	Current	0.1mA	1mA				
Set resolution	Power	U. IIIIA		10mA			
			10mW				
	Resistance	0.4	16bit	4 1			
Readback	Voltage		mV	1 mV			
esolution	Current	0.1mA	0.1mA	1mA			
	Power		10mW	(0.050/0.0050/.50)			
	Voltage	±(0.05%+0	·	±(0.05%+0.025%FS)			
	Current	±(0.1%+0.1%FS)	±(0.05%+0.05%FS)	±(0.05%+0.05%FS)			
et accuracy	Power*3		0.2%+0.2%FS	,			
	Resistance *1	0.01%+	0.08S *2	0.01%+0.0008S			
Readback	Voltage		±(0.025%+0.025%FS)				
	Current	±(0.1%+0.1%FS)		±(0.05%+0.05%FS)			
ccuracy	Power		±(0.2%+0.2%FS)				
et temperature drift	Voltage		≤100ppm/°C + 100ppm/°C*F\$	3			
pefficient(%of utput/ C+Offset)	Current		≤100ppm/°C + 100ppm/°C*FS	8			
eadback Temperature	Voltage	≤ 100ppm/°C + 100ppm/°C*FS					
ift coefficient((% of utput/ C +Offset)	Current	≤ 100ppm/°C + 100ppm/°C*FS					
utput = ronocty	Rising *4	$0.0001\sim0.1 ext{A/uS}$	$0.0001\sim0.5$ A/uS	$0.001\sim$ 5A/uS			
)vnamic	Falling*4	0.0001 ∼ 0.1A/uS	0.0001 ~ 0.5A/uS	$0.001\sim5$ A/uS			
,	Min.rising time*5	≒10uS	⇒10uS	5.001 574dS ≒10uS			
esponse	Dynamic frequency	1003	0.001 ∼ 20KHz	.1000			
	Voltage		110V ±10% or 220V ±10%				
	Frequency						
C parameter	Imax.	50/60Hz					
·	Power factor	0.3A > 0.00					
-t -t-billt : 00i-/0/		.(0.059/ .0.0	≥0.99	. (0 0E9/ . 0 02E9/ EQ)			
et stability-30min(%	Voltage	±(0.05%+0.0	,	±(0.05%+0.025%FS)			
f Output/ C +Offset)	Current	±(0.1%+0.1%FS)	±(0.05%+0.05%FS)	±(0.05%+0.05%FS)			
	Voltage	±(0.05%+0.0	,	±(0.05%+0.025%FS)			
utput/°C +Offset)	Current	±(0.1%+0.1%FS)	±(0.05%+0.05%FS)	±(0.05%+0.05%FS)			
eadback stability-30min	Voltage	. (0.10/ . 0.10/ 50)	±(0.025%+0.025%FS)	(0.000)			
of Output/ C+Offset)	Current	±(0.1%+0.1%FS)		±(0.05%+0.05%FS)			
eadback stability-8h	Voltage	(0.10/_0.10/_50)	±(0.025%+0.025%FS)	(0.050/ 0.050/50)			
of Output/ C+Offset)	Current	±(0.1%+0.1%FS)		±(0.05%+0.05%FS)			
Sense voltage			≤2V				
Storage temperature			-20°C ∼ 70°C				
	OPP	125W	610W	610W			
Protection	OCP	2.64A	13.2A	132A			
TOTOGUOIT	OVP	18	.5V	85V			
	OTP		100°C				
nterfaces			Ether Net, GPIB, USB, RS	232			
olation(output to ground)			500V/DC/1mA				
olation(input to ground)		1.5KV/AC/5mA					
nits parallel connected			≤16(channel)				
Protection level			IP20				
Safety regulation			IEC 61010				
Cooling			fan				
			0 ~ 40°C				
Vorking temperature		0 ~ 40 € 82mm*183mm*573mm					
Dimension(mm) N.W.							
V. VV.			5kg				

^{*1} Input voltage/current is not less than 10%FS (FS is full scale)

^{*2} Range of resistance readback value: (1/(1/R+(1/R)*0.01%+0.08),1/(1/R-(1/R)*0.01%-0.08))

 $^{^{*}3}$ Input voltage/current is not less than 10%FS

^{*4} Rise/fall slew rate: 10%~90% of current rising from 0 to Max.current

^{*5} Minimum rise time: 10%~90% of current rise time



This information is subject to change without notice. For more information, please contact ITECH.

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